NSN 5962-01-193-5815

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-193-5815

Body Length:

Between 1.230 inches and 1.285 inches

Body Width:

Between 0.510 inches and 0.545 inches

Body Height:

Between 0.135 inches and 0.165 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Simulator an/ulq-13

Features Provided:

Hermetically sealed and static operation and w/enable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Metal oxide-semiconductor logic

Input Circuit Pattern:

22 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

70.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

NSN 5962-01-193-5815

Memory Microcircuit - Page 2 of 2

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